# RGS Focal Plane Camera (RFC) Technology and Implementation Status

George Ricker, on behalf of the MIT Con-X RFC Team (John Doty, Steve Kissel, Gregory Prigozhin)

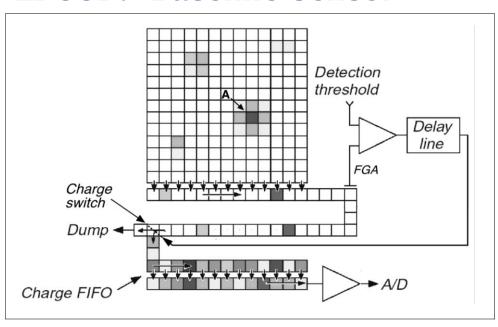
Constellation X
Facility Science Team Meeting
Goddard Space Flight Center
20 November 2003

- Review of Event Driven CCD
- Progress in Back-illuminated CCD Technology
- Implications for Extended (E<sub>x</sub> < 0.25 keV) Low Energy Response
- Concept for an Offplane Grating Readout

# **Key Technology Drivers for RFC**

- High QE for 0.25 2 keV band
- High yield for back-illuminated CCDs
- Adequate energy resolution at low E<sub>x</sub>
  - Grating order separation
  - Particle background rejection
- Radiation tolerant at L2
- Stable Calibration
  - Near room temperature operation
  - Pile up resistant

## **EDCCD: Baseline Sensor**

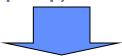


## System Constraints relief for Con-X

- Lower power dissipation at a given frame rate (>100 x less)
- Enables integrated flight camera testing at room temperature
- Compatible with broad operating temperature range (~ 0° C to -120° C)
- Reduced shielding requirement (>10x more radhard)
- High frame rate: relaxed S/C stability and jitter requirements

## Event-Driven CCD: Advantages

- Pixels are non-destructively sensed, and only those with signal charge are saved and digitized
- Compatible with high yield BI processes
- High speed: 100 x Chandra/ACIS (greatly reduced pileup)



## Additional Advantages of EDCCD

- Improved QE for 0.2 2 keV band
- High frame rate (30-50 Hz); thus, can use thinner optical blocking filter (OBF)
- High yields and reduced risk
  - Conventional MOS CCD processing
  - Compilation of separately-tested innovations
  - Flight-proven (ASCA, Chandra) key elements
    - Parallel register array
    - Low noise floating diffusion output amplifier

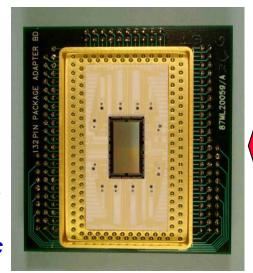




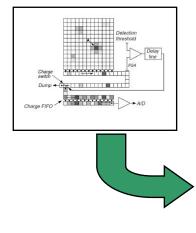
# **EDCCD Technology Status**

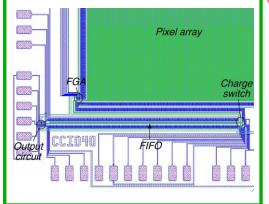
## Gen 1-Lot 1 EDCCD

- 512 x 512 prototype
- Unthinned Device
- Tested Excellent Performance as "standard CCD"
- Special drive electronics for ED operation in test
- Full EDCCD mode in Dec



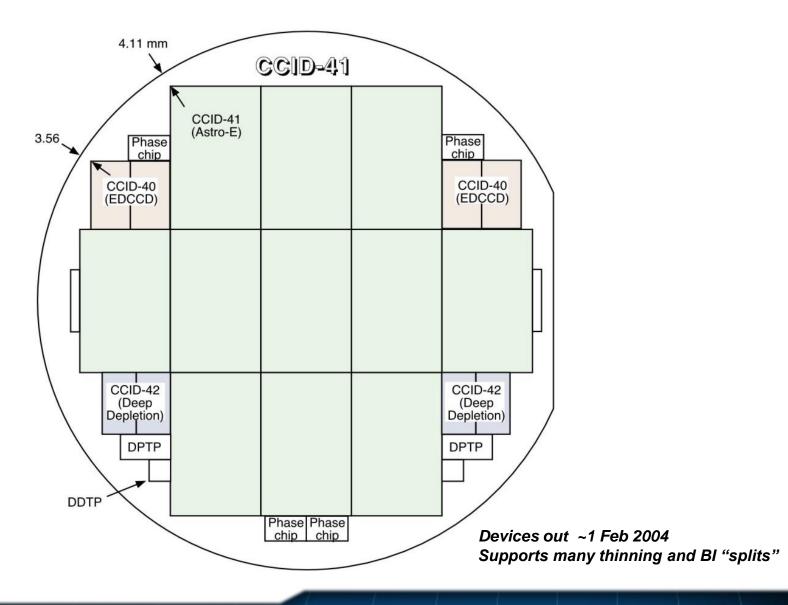






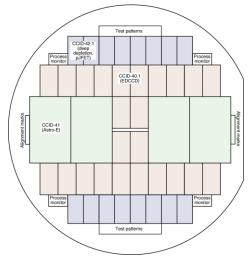


# **EDCCD Gen 1-Lot 2 Wafer Layout: Fab in Progress**



## EDCCD Gen 1.5 — Lot 1 Status

## New wafer layout



# Mechanism for improved tolerance to radiation damage

Under irradiation vacancies and interstitials are formed.

Then the following reactions producing electron traps take place:

$$V + V \rightarrow V-V$$
 (divacancy)

$$V + P \rightarrow P-V$$
 (P-V center)

Diffusion of Oxygen increases its concentration by a factor of 20.

This strongly shifts equilibrium to the last reaction.

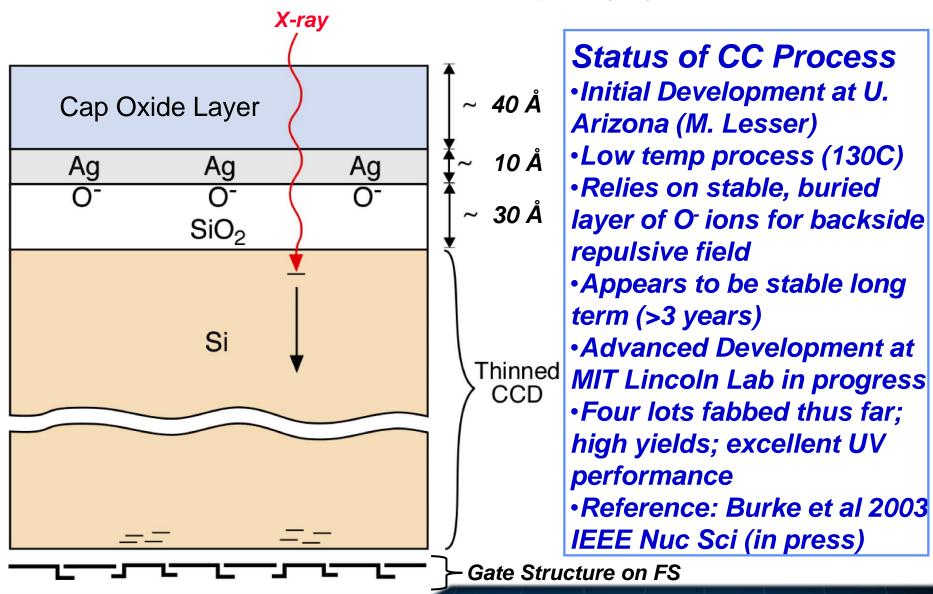
Formation of the most damaging V-V and P-V centers is suppressed.

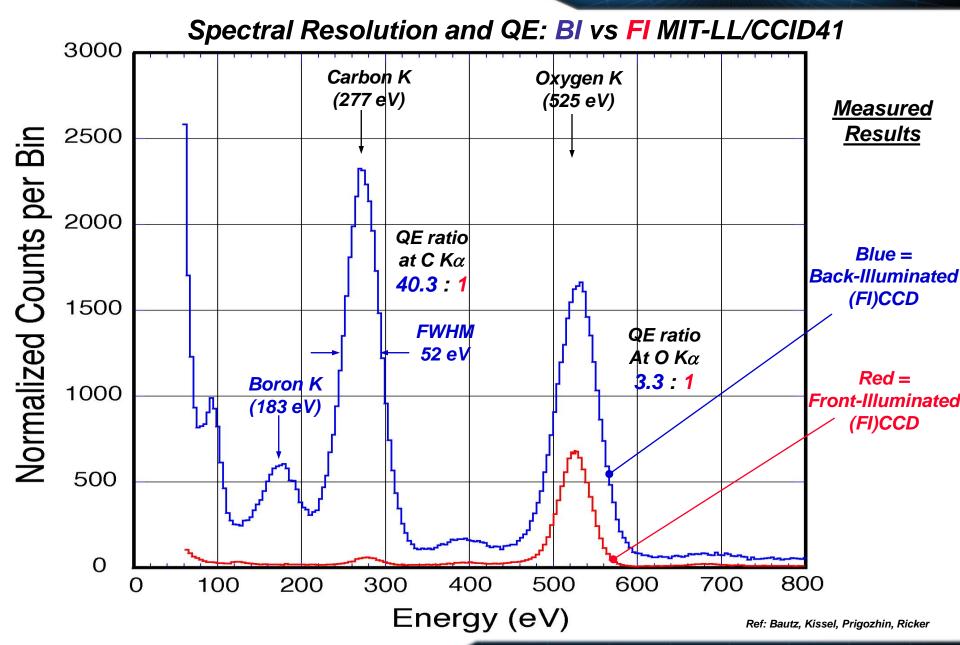
- Wafer layout has been determined (see figure on the right).
- Wafers have been selected (6
   Wacker 5000 Ohm cm wafers + 6
   Topsil 9000 Ohm cm wafers) and
   preliminary high temperature
   processing has been completed.
- Sample wafers will undergo "oxygenation" in order to improve radiation tolerance (mechanism is explained on the left).
- Improved output stage (for high speed readout) has been incorporated into the device. A new test structure for a very high sensitivity output (>20 μV/e<sup>-</sup>) is being designed.
- Lot completion ~15 May 2004;
   wafers will be thinnable.



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# Cross Section of "Chemisorption-charged" (CC) BI CCD



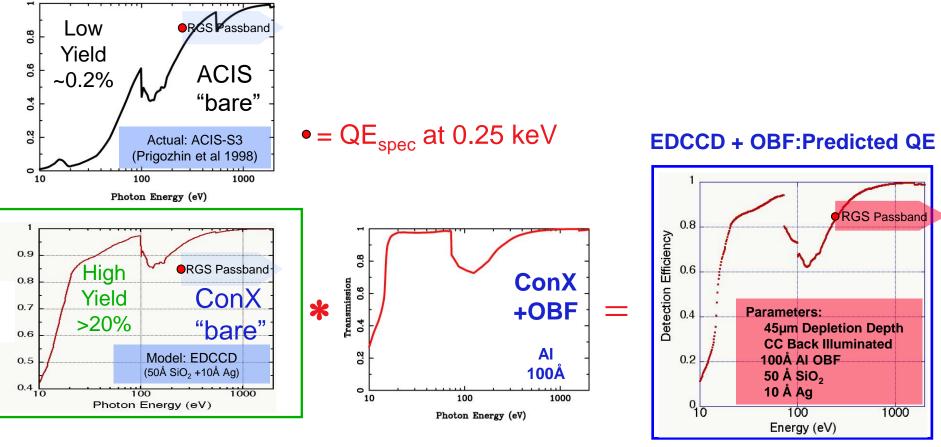




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# **Quantum Efficiency Comparison: ACIS-S3 (BI) vs EDCCD (BI)**

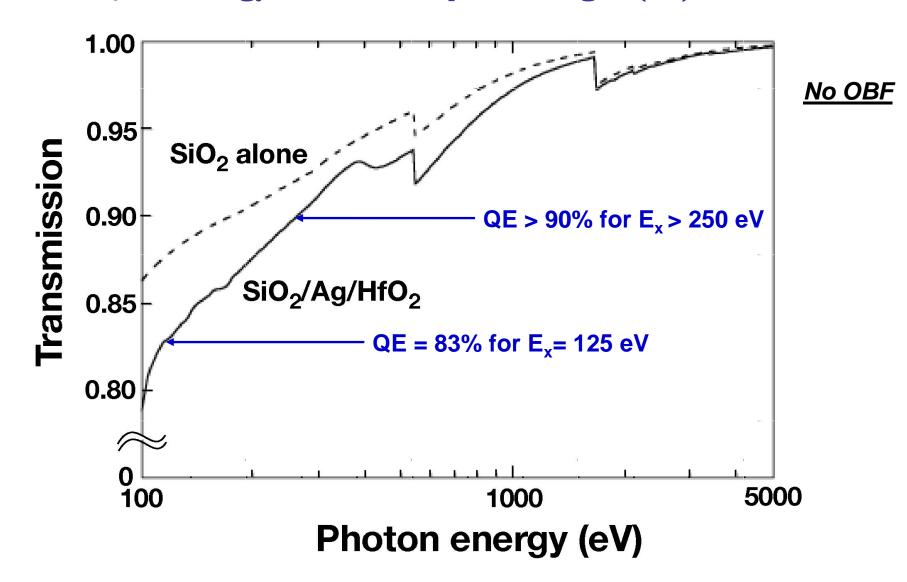
Plots at left show QE of "bare CCD" ie no optical blocking filter (OBF)



### **Conclusions:**

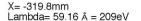
- An EDCCD can use >10x thinner OBF than ACIS >>> higher X-ray transmission at low E<sub>x</sub>
- Back-illuminated EDCCD should meet Con-X low energy QE specification

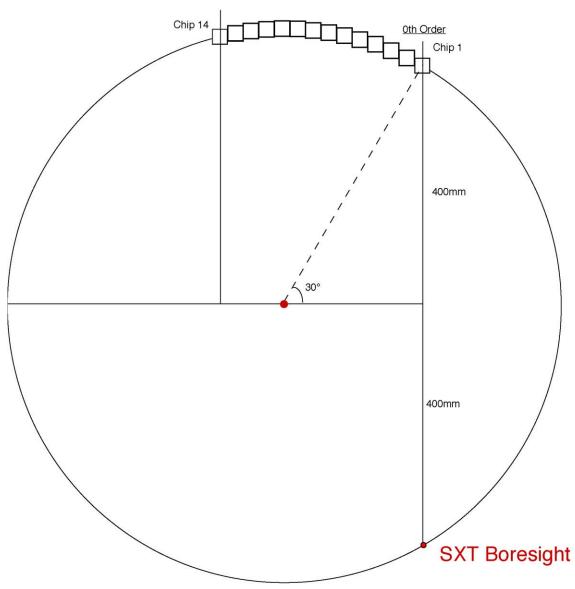
# Calculated QE vs Energy for Chemisorption-charged (CC) BI CCD





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# **CCD Detector** Array for Off-Plane Grating:

- -1Kx1K EDCCD
- -Off Plane 5800 lp/mm
- -Scale Drawing

#### Scales:

20.6 arcsec/mm

- =0.49 arcsec/pixel =8.4 arcmin/chip

#### **Dispersion:**

- 4.45 må/pixel
- = 0.016 eV/pixel @ 209 eV
- = 0.032 eV/arcsec @ 209 eV
- = 0.064 eV/(2arcsec) @ 209 eV =>R=3300 @ 209eV

## **Near Term Development Focus for RGS Focal Plane Camera**

## EDCCDs:

- Complete Fab of Gen 1-Lot 2 (in process; devices in Feb '04)
- Lot Fab for Gen 1.5-Lot1 (lot start ~15 Dec; complete in May '04)
- Layout for Gen 2 EDCCD (lot start ~ 15 Mar '04)
- EDCCD mode testing of Gen 1-Lot 1 packaged devices
- Continue QE measurements at E<sub>x</sub> = 0.25 keV and below
  - CC process modelling
  - Radiation damage testing of CC devices
  - Accelerated stability testing and cycling of CC devices
- Assess camera impacts for:
  - $E_{x, low}$  < 0.25 keV (ie  $E_{x, low}$ = 0.125 keV would double array length)
  - Off plane design (ie crescent-shaped focal plane)